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# FSAM15SH60A

## Motion SPM® 2 Series

### Features

- UL Certified No. E209204 (UL1557)
- 600 V - 15 A 3-Phase IGBT Inverter with Integral Gate Drivers and Protection
- Low-Loss, Short-Circuit Rated IGBTs
- Low Thermal Resistance Using Ceramic Substrate
- Separate Open-Emitter Pins from Low Side IGBTs for Three-Phase Current Sensing
- Single-Grounded Power Supply
- Optimized for 15 kHz Switching Frequency
- Built-in NTC Thermistor for Temperature Monitoring
- Inverter Power Rating of 0.8 kW / 100~253 VAC
- Adjustable Current Protection Level via Selection of Sense-IGBT Emitter's External Rs
- Isolation Rating: 2500 V<sub>rms</sub> / min.

### Applications

- Motion Control - Home Appliance / Industrial Motor

### Resource

- [AN-9043 - Motion SPM® 2 Series User's Guide](#)

### General Description

FSAM15SH60A is a Motion SPM® 2 module providing a fully-featured, high-performance inverter stage for AC Induction, BLDC, and PMSM motors. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts, over-current shutdown, thermal monitoring, and fault reporting. The built-in, high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's internal IGBTs. Separate negative IGBT terminals are available for each phase to support the widest variety of control algorithms.



Figure 1. Package Overview

### Package Marking and Ordering Information

| Device      | Device Marking | Package   | Packing Type | Quantity |
|-------------|----------------|-----------|--------------|----------|
| FSAM15SH60A | FSAM15SH60A    | S32AA-032 | Rail         | 8        |

## Integrated Power Functions

- 600V - 15 A IGBT inverter for three-phase DC / AC power conversion (please refer to Figure 3)

## Integrated Drive, Protection and System Control Functions

- For inverter high-side IGBTs: gate drive circuit, high-voltage isolated high-speed level shifting control circuit Under-Voltage Lock-Out (UVLO) Protection  
Note) Available bootstrap circuit example is given in Figures 13 and 14.
- For inverter low-side IGBTs: gate drive circuit, Short-Circuit Protection (SCP) control supply circuit Under-Voltage Lock-Out (UVLO) Protection
- Temperature Monitoring: system temperature monitoring using built-in thermistor  
Note) Available temperature monitoring circuit is given in Figure 14.
- Fault signaling: corresponding to a SC fault (low-side IGBTs) and UV fault (low-side control supply)
- Input interface: active-LOW Interface, works with 3.3 / 5 V logic, Schmitt-trigger input

## Pin Configuration

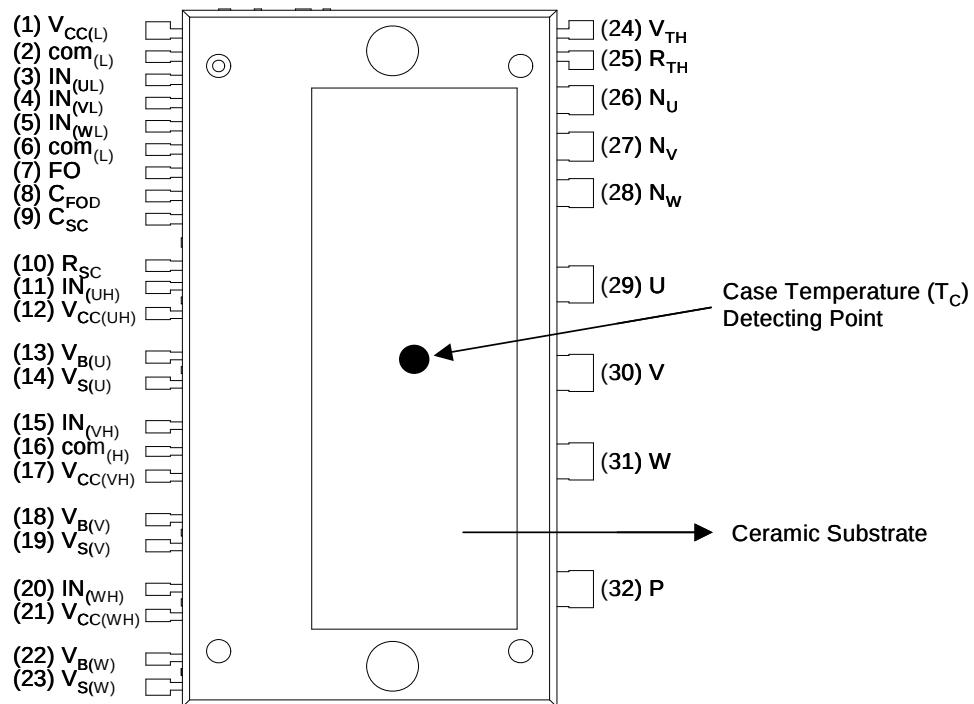


Figure 2. Top View

## Pin Descriptions

| Pin Number | Pin Name     | Pin Description                                                       |
|------------|--------------|-----------------------------------------------------------------------|
| 1          | $V_{CC(L)}$  | Low-Side Common Bias Voltage for IC and IGBTs Driving                 |
| 2          | $COM_{(L)}$  | Low-Side Common Supply Ground                                         |
| 3          | $IN_{(UL)}$  | Signal Input Terminal for Low-Side U-Phase                            |
| 4          | $IN_{(VL)}$  | Signal Input Terminal for Low-Side V-Phase                            |
| 5          | $IN_{(WL)}$  | Signal Input Terminal for Low-Side W-Phase                            |
| 6          | $COM_{(L)}$  | Low-Side Common Supply Ground                                         |
| 7          | $V_{FO}$     | Fault Output                                                          |
| 8          | $C_{FOD}$    | Capacitor for Fault Output Duration Selection                         |
| 9          | $C_{SC}$     | Capacitor (Low-Pass Filter) for Short-Circuit Current Detection Input |
| 10         | $R_{SC}$     | Resistor for Short-Circuit Current Detection                          |
| 11         | $IN_{(UH)}$  | Signal Input for High-Side U-Phase                                    |
| 12         | $V_{CC(UH)}$ | High-Side Bias Voltage for U-Phase IC                                 |
| 13         | $V_{B(U)}$   | High-Side Bias Voltage for U-Phase IGBT Driving                       |
| 14         | $V_{S(U)}$   | High-Side Bias Voltage Ground for U-Phase IGBT Driving                |
| 15         | $IN_{(VH)}$  | Signal Input for High-Side V-Phase                                    |
| 16         | $COM_{(H)}$  | High-Side Common Supply Ground                                        |
| 17         | $V_{CC(VH)}$ | High-Side Bias Voltage for V-Phase IC                                 |
| 18         | $V_{B(V)}$   | High-Side Bias Voltage for V-Phase IGBT Driving                       |
| 19         | $V_{S(V)}$   | High-Side Bias Voltage Ground for V-Phase IGBT Driving                |
| 20         | $IN_{(WH)}$  | Signal Input for High-side W-Phase                                    |
| 21         | $V_{CC(WH)}$ | High-Side Bias Voltage for W-Phase IC                                 |
| 22         | $V_{B(W)}$   | High-Side Bias Voltage for W-Phase IGBT Driving                       |
| 23         | $V_{S(W)}$   | High-Side Bias Voltage Ground for W-Phase IGBT Driving                |
| 24         | $V_{TH}$     | Thermistor Bias Voltage                                               |
| 25         | $R_{TH}$     | Series Resistor for the Use of Thermistor (Temperature Detection)     |
| 26         | $N_U$        | Negative DC-Link Input Terminal for U-Phase                           |
| 27         | $N_V$        | Negative DC-Link Input Terminal for V-Phase                           |
| 28         | $N_W$        | Negative DC-Link Input Terminal for W-Phase                           |
| 29         | U            | Output for U-Phase                                                    |
| 30         | V            | Output for V-Phase                                                    |
| 31         | W            | Output for W-Phase                                                    |
| 32         | P            | Positive DC-Link Input                                                |

## Internal Equivalent Circuit and Input/Output Pins

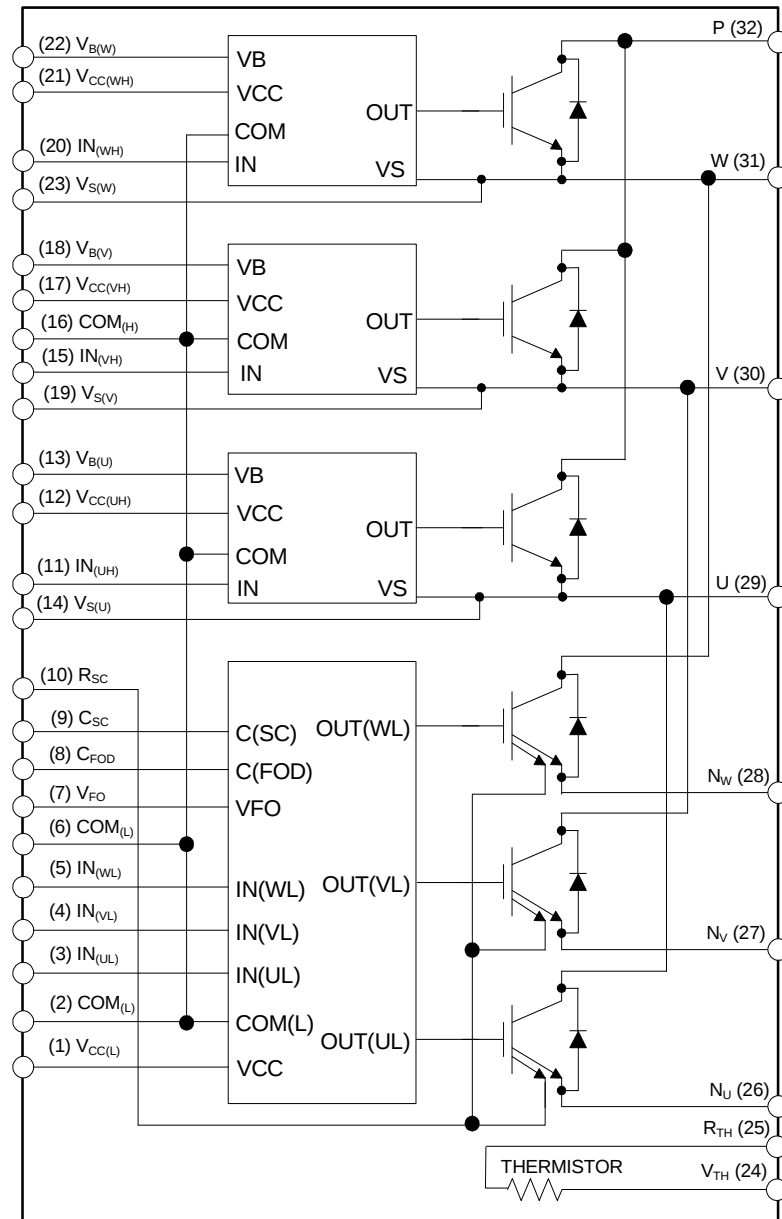


Figure 3. Internal Block Diagram

### 1st Notes:

1. Inverter low-side is composed of three sense-IGBTs including freewheeling diodes for each IGBT and one control IC which has gate driving, current-sensing and protection functions.
2. Inverter power side is composed of four inverter DC-link input pins and three inverter output pins.
3. Inverter high-side is composed of three normal-IGBTs including freewheeling diodes and three drive ICs for each IGBT.

**Absolute Maximum Ratings** ( $T_J = 25^\circ\text{C}$ , unless otherwise specified.)**Inverter Part**

| Item                               | Symbol                 | Condition                                        | Rating    | Unit             |
|------------------------------------|------------------------|--------------------------------------------------|-----------|------------------|
| Supply Voltage                     | $V_{DC}$               | Applied to DC-Link                               | 450       | V                |
| Supply Voltage (Surge)             | $V_{PN(\text{Surge})}$ | Applied between P and N                          | 500       | V                |
| Collector - Emitter Voltage        | $V_{CES}$              |                                                  | 600       | V                |
| Each IGBT Collector Current        | $\pm I_C$              | $T_C = 25^\circ\text{C}$                         | 15        | A                |
| Each IGBT Collector Current        | $\pm I_C$              | $T_C = 100^\circ\text{C}$                        | 11        | A                |
| Each IGBT Collector Current (Peak) | $\pm I_{CP}$           | $T_C = 25^\circ\text{C}$ , Under 1ms Pulse Width | 30        | A                |
| Collector Dissipation              | $P_C$                  | $T_C = 25^\circ\text{C}$ per Chip                | 50        | W                |
| Operating Junction Temperature     | $T_J$                  | (2nd Note 1)                                     | -20 ~ 125 | $^\circ\text{C}$ |

**2nd Notes:**

1. It would be recommended that the average junction temperature should be limited to  $T_J \leq 125^\circ\text{C}$  (at  $T_C \leq 100^\circ\text{C}$ ) in order to guarantee safe operation.

**Control Part**

| Item                           | Symbol   | Condition                                                                                                                     | Rating              | Unit |
|--------------------------------|----------|-------------------------------------------------------------------------------------------------------------------------------|---------------------|------|
| Control Supply Voltage         | $V_{CC}$ | Applied between $V_{CC(UH)}$ , $V_{CC(VH)}$ , $V_{CC(WH)}$ - $COM_{(H)}$ , $V_{CC(L)}$ - $COM_{(L)}$                          | 20                  | V    |
| High-Side Control Bias Voltage | $V_{BS}$ | Applied between $V_{B(U)} - V_{S(U)}$ , $V_{B(V)} - V_{S(V)}$ , $V_{B(W)} - V_{S(W)}$                                         | 20                  | V    |
| Input Signal Voltage           | $V_{IN}$ | Applied between $IN_{(UH)}$ , $IN_{(VH)}$ , $IN_{(WH)}$ - $COM_{(H)}$ , $IN_{(UL)}$ , $IN_{(VL)}$ , $IN_{(WL)}$ - $COM_{(L)}$ | -0.3 ~ $V_{CC}+0.3$ | V    |
| Fault Output Supply Voltage    | $V_{FO}$ | Applied between $V_{FO}$ - $COM_{(L)}$                                                                                        | -0.3 ~ $V_{CC}+0.3$ | V    |
| Fault Output Current           | $I_{FO}$ | Sink Current at $V_{FO}$ Pin                                                                                                  | 5                   | mA   |
| Current-Sensing Input Voltage  | $V_{SC}$ | Applied between $C_{SC}$ - $COM_{(L)}$                                                                                        | -0.3 ~ $V_{CC}+0.3$ | V    |

**Total System**

| Item                                                                       | Symbol                | Condition                                                                                                                        | Rating    | Unit             |
|----------------------------------------------------------------------------|-----------------------|----------------------------------------------------------------------------------------------------------------------------------|-----------|------------------|
| Self-Protection Supply Voltage Limit (Short-Circuit Protection Capability) | $V_{PN(\text{PROT})}$ | Applied to DC-Link, $V_{CC} = V_{BS} = 13.5 \sim 16.5 \text{ V}$ , $T_J = 125^\circ\text{C}$ , Non-Repetitive, $< 6 \mu\text{s}$ | 400       | V                |
| Module Case Operation Temperature                                          | $T_C$                 | See Figure 2                                                                                                                     | -20 ~ 100 | $^\circ\text{C}$ |
| Storage Temperature                                                        | $T_{STG}$             |                                                                                                                                  | -20 ~ 125 | $^\circ\text{C}$ |
| Isolation Voltage                                                          | $V_{ISO}$             | 60Hz, Sinusoidal, AC 1 Minute, Connect Pins to Heat Sink Plate                                                                   | 2500      | $V_{rms}$        |

**Thermal Resistance**

| Item                                | Symbol         | Condition                                                               | Min. | Typ. | Max. | Unit               |
|-------------------------------------|----------------|-------------------------------------------------------------------------|------|------|------|--------------------|
| Junction to Case Thermal Resistance | $R_{th(j-c)Q}$ | Inverter IGBT Part (per 1/6 module)                                     | -    | -    | 2.50 | $^\circ\text{C/W}$ |
|                                     | $R_{th(j-c)F}$ | Inverter FWDi Part (per 1/6 module)                                     | -    | -    | 3.60 | $^\circ\text{C/W}$ |
| Contact Thermal Resistance          | $R_{th(c-f)}$  | Ceramic Substrate (per 1 Module)<br>Thermal Grease Applied (2nd Note 3) | -    | -    | 0.06 | $^\circ\text{C/W}$ |

**2nd Notes:**

2. For the measurement point of case temperature( $T_C$ ), please refer to Figure 2.  
 3. The thickness of thermal grease should not be more than 100  $\mu\text{m}$ .

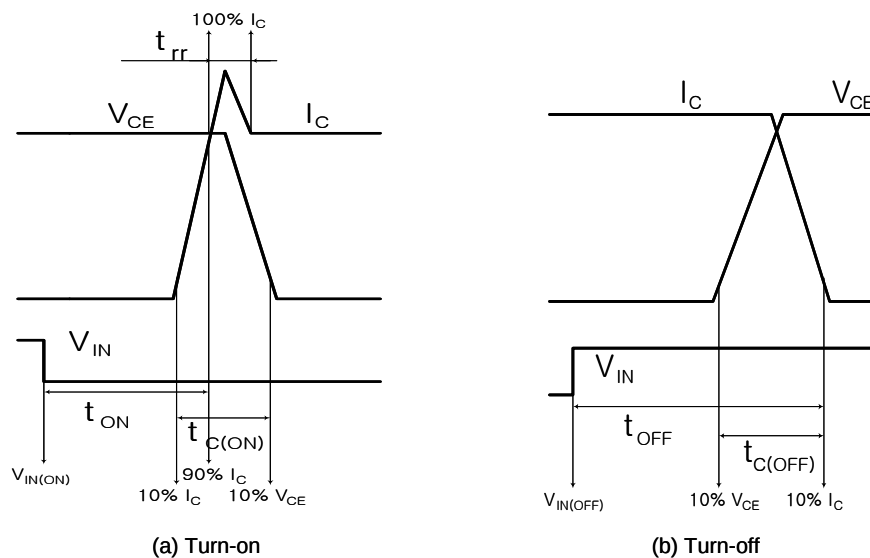
## Electrical Characteristics

**Inverter Part** ( $T_J = 25^\circ\text{C}$ , unless otherwise specified.)

| Item                                   | Symbol        | Condition                                                                                                   | Min. | Typ. | Max. | Unit          |
|----------------------------------------|---------------|-------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| Collector - Emitter Saturation Voltage | $V_{CE(SAT)}$ | $V_{CC} = V_{BS} = 15\text{ V}$<br>$V_{IN} = 0\text{ V}$                                                    | -    | -    | 2.50 | V             |
|                                        |               | $I_C = 15\text{ A}$ , $T_J = 125^\circ\text{C}$                                                             | -    | -    | 2.60 | V             |
| FWDi Forward Voltage                   | $V_{FM}$      | $V_{IN} = 5\text{ V}$                                                                                       | -    | -    | 2.50 | V             |
|                                        |               | $I_C = 15\text{ A}$ , $T_J = 125^\circ\text{C}$                                                             | -    | -    | 2.30 | V             |
| Switching Times                        | $t_{ON}$      | $V_{PN} = 300\text{ V}$ , $V_{CC} = V_{BS} = 15\text{ V}$<br>$I_C = 15\text{ A}$ , $T_J = 25^\circ\text{C}$ | -    | 0.34 | -    | $\mu\text{s}$ |
|                                        | $t_{C(ON)}$   | $V_{IN} = 5\text{ V} \leftrightarrow 0\text{ V}$ , Inductive Load<br>(High, Low-side)                       | -    | 0.15 | -    | $\mu\text{s}$ |
|                                        | $t_{OFF}$     |                                                                                                             | -    | 0.73 | -    | $\mu\text{s}$ |
|                                        | $t_{C(OFF)}$  |                                                                                                             | -    | 0.24 | -    | $\mu\text{s}$ |
|                                        | $t_{rr}$      | (2nd Note 4)                                                                                                | -    | 0.13 | -    | $\mu\text{s}$ |
| Collector - Emitter Leakage Current    | $I_{CES}$     | $V_{CE} = V_{CES}$ , $T_J = 25^\circ\text{C}$                                                               | -    | -    | 250  | $\mu\text{A}$ |

### 2nd Notes:

4.  $t_{ON}$  and  $t_{OFF}$  include the propagation delay time of the internal drive IC.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.



**Figure 4. Switching Time Definition**

## Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise specified.)

### Control Part

| Item                                     | Symbol               | Condition                                                                                                                      | Min. | Typ. | Max. | Unit |
|------------------------------------------|----------------------|--------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| Quiescent V <sub>CC</sub> Supply Current | I <sub>QCCL</sub>    | V <sub>CC</sub> = 15 V<br>IN <sub>(UL, VL, WL)</sub> = 5V                                                                      | -    | -    | 26   | mA   |
|                                          | I <sub>QCCH</sub>    | V <sub>CC</sub> = 15 V<br>IN <sub>(UH, VH, WH)</sub> = 5V                                                                      | -    | -    | 130  | μA   |
| Quiescent V <sub>BS</sub> Supply Current | I <sub>QBS</sub>     | V <sub>BS</sub> = 15 V<br>IN <sub>(UH, VH, WH)</sub> = 5V                                                                      | -    | -    | 420  | μA   |
| Fault Output Voltage                     | V <sub>FOH</sub>     | V <sub>SC</sub> = 0 V, V <sub>FO</sub> Circuit: 4.7 kΩ to 5 V Pull-up                                                          | 4.5  | -    | -    | V    |
|                                          | V <sub>FOL</sub>     | V <sub>SC</sub> = 1 V, V <sub>FO</sub> Circuit: 4.7 kΩ to 5 V Pull-up                                                          | -    | -    | 1.1  | V    |
| Short-Circuit Trip Level                 | V <sub>SC(ref)</sub> | V <sub>CC</sub> = 15 V (Note 5)                                                                                                | 0.45 | 0.51 | 0.56 | V    |
| Sensing Voltage of IGBT Current          | V <sub>SEN</sub>     | R <sub>SC</sub> = 50 Ω, R <sub>SU</sub> = R <sub>SV</sub> = R <sub>SW</sub> = 0 Ω and I <sub>C</sub> = 22.5 A (See a Figure 6) | 0.45 | 0.51 | 0.56 | V    |
| Supply Circuit Under-Voltage Protection  | UV <sub>CCD</sub>    | Detection Level                                                                                                                | 11.5 | 12.0 | 12.5 | V    |
|                                          | UV <sub>CCR</sub>    | Reset Level                                                                                                                    | 12.0 | 12.5 | 13.0 | V    |
|                                          | UV <sub>BSD</sub>    | Detection Level                                                                                                                | 7.3  | 9.0  | 10.8 | V    |
|                                          | UV <sub>BSR</sub>    | Reset Level                                                                                                                    | 8.6  | 10.3 | 12.0 | V    |
| Fault Output Pulse Width                 | t <sub>FOD</sub>     | C <sub>FOD</sub> = 33 nF (2nd Note 6)                                                                                          | 1.4  | 1.8  | 2.0  | ms   |
| ON Threshold Voltage                     | V <sub>IN(ON)</sub>  | High-Side                                                                                                                      | -    | -    | 0.8  | V    |
| OFF Threshold Voltage                    | V <sub>IN(OFF)</sub> | Applied between IN <sub>(UH)</sub> , IN <sub>(VH)</sub> , IN <sub>(WH)</sub> - COM <sub>(H)</sub>                              | 3.0  | -    | -    | V    |
| ON Threshold Voltage                     | V <sub>IN(ON)</sub>  | Low-Side                                                                                                                       | -    | -    | 0.8  | V    |
| OFF Threshold Voltage                    | V <sub>IN(OFF)</sub> | Applied between IN <sub>(UL)</sub> , IN <sub>(VL)</sub> , IN <sub>(WL)</sub> - COM <sub>(L)</sub>                              | 3.0  | -    | -    | V    |
| Resistance of Thermistor                 | R <sub>TH</sub>      | @ T <sub>TH</sub> = 25°C (2nd Note 7, Figure 5)                                                                                | -    | 50   | -    | kΩ   |
|                                          |                      | @ T <sub>TH</sub> = 100°C (2nd Note 7, Figure 5)                                                                               | -    | 3.4  | -    | kΩ   |

#### 2nd Notes:

- Short-circuit protection is functioning only at the low-sides. It would be recommended that the value of the external sensing resistor (R<sub>SC</sub>) should be selected around 50 Ω in order to make the SC trip-level of about 22.5A at the shunt resistors (R<sub>SU</sub>, R<sub>SV</sub>, R<sub>SW</sub>) of 0 Ω. For the detailed information about the relationship between the external sensing resistor (R<sub>SC</sub>) and the shunt resistors (R<sub>SU</sub>, R<sub>SV</sub>, R<sub>SW</sub>), please see Figure 6.
- The fault-out pulse width t<sub>FOD</sub> depends on the capacitance value of C<sub>FOD</sub> according to the following approximate equation: C<sub>FOD</sub> = 18.3 × 10<sup>-6</sup> × t<sub>FOD</sub> [F]
- T<sub>TH</sub> is the temperature of thermistor itself. To know case temperature (T<sub>C</sub>), please make the experiment considering your application.

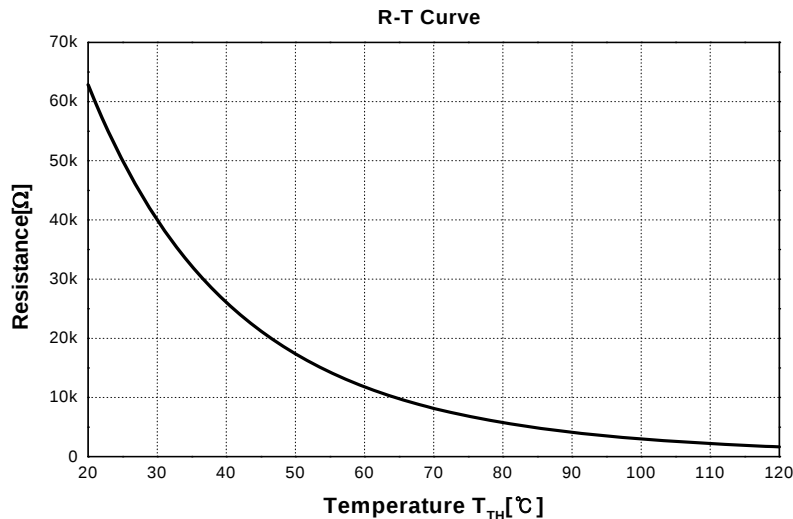
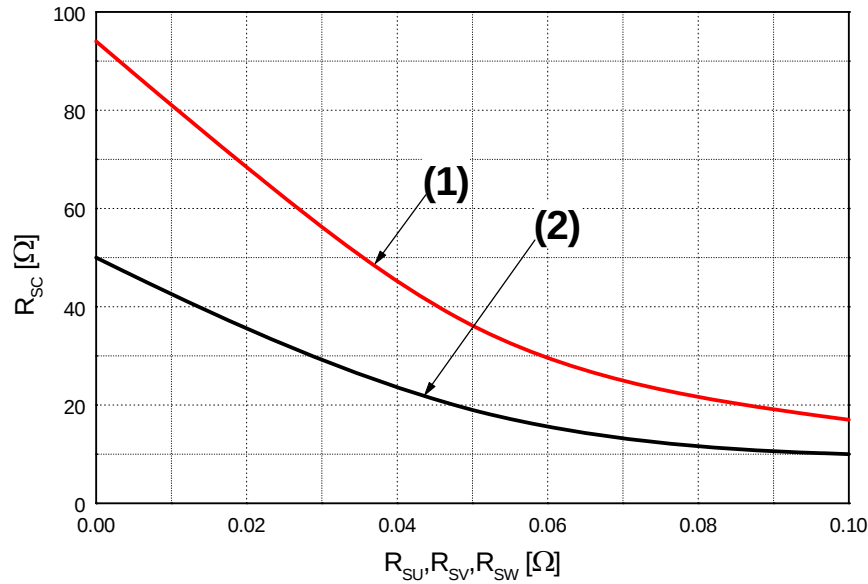


Figure 5. R-T Curve of The Built-in Thermistor



**Figure 6. R<sub>SC</sub> Variation by Change of Shunt Resistors ( R<sub>SU</sub>, R<sub>SV</sub>, R<sub>SW</sub>) for Short-Circuit Protection**  
**(1) @ Current Trip Level ≈ 15.0 A**  
**(2) @ Current Trip Level ≈ 22.5 A**

## Recommended Operating Conditions

| Item                                   | Symbol                | Condition                                                                                                                                                                                                            | Min.     | Typ. | Max. | Unit |
|----------------------------------------|-----------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|------|------|------|
| Supply Voltage                         | V <sub>PN</sub>       | Applied between P - N <sub>U</sub> , N <sub>V</sub> , N <sub>W</sub>                                                                                                                                                 | -        | 300  | 400  | V    |
| Control Supply Voltage                 | V <sub>CC</sub>       | Applied between V <sub>CC(UH)</sub> , V <sub>CC(VH)</sub> , V <sub>CC(WH)</sub> - COM <sub>(H)</sub> , V <sub>CC(L)</sub> - COM <sub>(L)</sub>                                                                       | 13.5     | 15.0 | 16.5 | V    |
| High-side Bias Voltage                 | V <sub>BS</sub>       | Applied between V <sub>B(U)</sub> - V <sub>S(U)</sub> , V <sub>B(V)</sub> - V <sub>S(V)</sub> , V <sub>B(W)</sub> - V <sub>S(W)</sub>                                                                                | 13.0     | 15.0 | 18.5 | V    |
| Blanking Time for Preventing Arm-short | t <sub>dead</sub>     | For Each Input Signal                                                                                                                                                                                                | 2.0      | -    | -    | μs   |
| PWM Input Signal                       | f <sub>PWM</sub>      | T <sub>C</sub> ≤ 100°C, T <sub>J</sub> ≤ 125°C                                                                                                                                                                       | -        | 15   | -    | kHz  |
| Minimum Input Pulse Width              | PW <sub>IN(OFF)</sub> | 200 ≤ V <sub>PN</sub> ≤ 400 V, 13.5 ≤ V <sub>CC</sub> ≤ 16.5 V, 13.0 ≤ V <sub>BS</sub> ≤ 18.5 V, 0 ≤ I <sub>C</sub> ≤ 30 A, -20 ≤ T <sub>J</sub> ≤ 125°C<br>V <sub>IN</sub> = 5 V ↔ 0 V, Inductive Load (2nd Note 8) | 3        | -    | -    | μs   |
| Input ON Threshold Voltage             | V <sub>IN(ON)</sub>   | Applied between IN <sub>(UH)</sub> , IN <sub>(VH)</sub> , IN <sub>(WH)</sub> - COM <sub>(H)</sub> , IN <sub>(UL)</sub> , IN <sub>(VL)</sub> , IN <sub>(WL)</sub> - COM <sub>(L)</sub>                                | 0 ~ 0.65 |      |      | V    |
| Input OFF Threshold Voltage            | V <sub>IN(OFF)</sub>  | Applied between IN <sub>(UH)</sub> , IN <sub>(VH)</sub> , IN <sub>(WH)</sub> - COM <sub>(H)</sub> , IN <sub>(UL)</sub> , IN <sub>(VL)</sub> , IN <sub>(WL)</sub> - COM <sub>(L)</sub>                                | 4 ~ 5.5  |      |      | V    |

### 2nd Notes:

8. Motion SPM® 2 product might not make response if the PW<sub>IN(OFF)</sub> is less than the recommended minimum value.

## Mechanical Characteristics and Ratings

| Item             | Condition                                 |                      | Min. | Typ. | Max. | Units |
|------------------|-------------------------------------------|----------------------|------|------|------|-------|
| Mounting Torque  | Mounting Screw: M4<br>(2nd Note 9 and 10) | Recommended 10 kg•cm | 8    | 10   | 12   | kg•cm |
|                  |                                           | Recommended 0.98 N•m | 0.78 | 0.98 | 1.17 | N•m   |
| Ceramic Flatness |                                           | See Figure 7         | 0    | -    | +120 | μm    |
| Weight           |                                           |                      | -    | 35   | -    | g     |

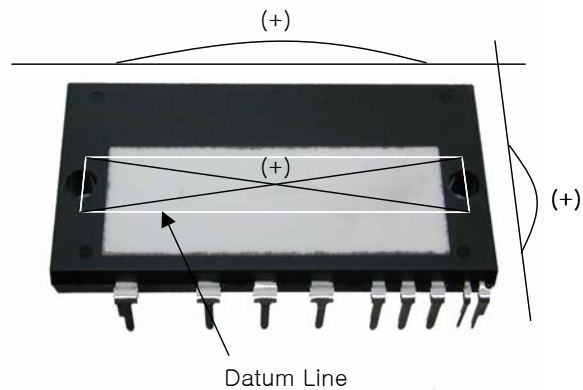


Figure 7. Flatness Measurement Position of The Ceramic Substrate

**2nd Notes:**

9. Do not make over torque or mounting screws. Much mounting torque may cause ceramic substrate cracks and bolts and Al heat-sink destruction.  
 10. Avoid one side tightening stress. Figure 8 shows the recommended torque order for mounting screws. Uneven mounting can cause the Motion SPM® 2 package ceramic substrate to be damaged.

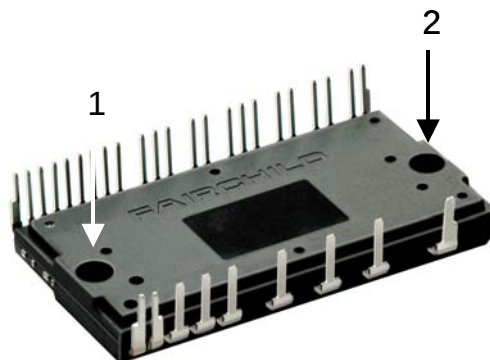
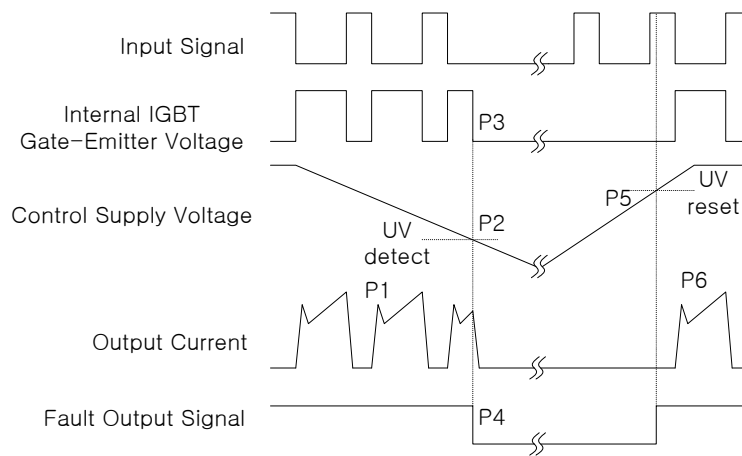


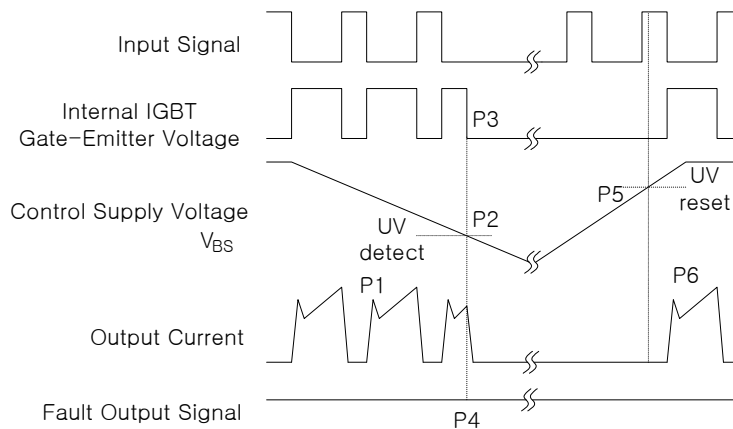
Figure 8. Mounting Screws Torque Order (1 → 2)

## Time Charts of Protective Function



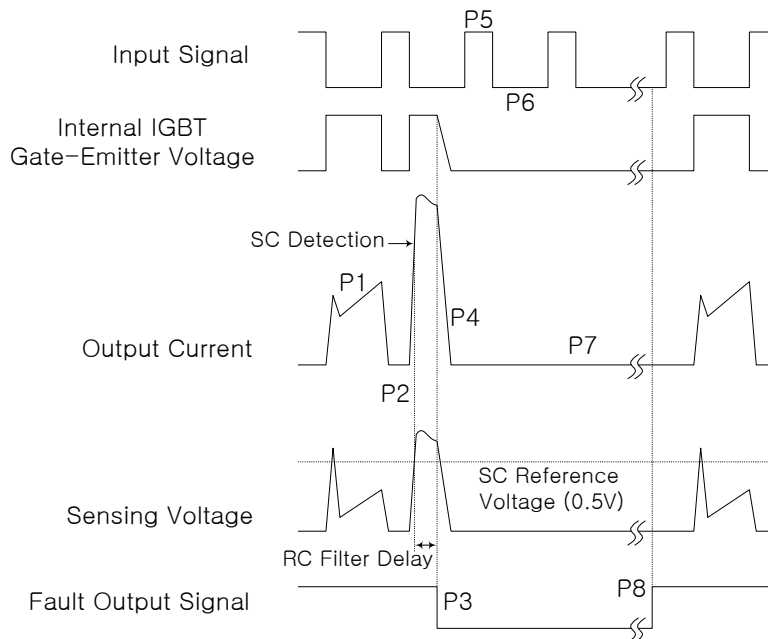
- P1 : Normal operation: IGBT ON and conducting current .  
P2 : Under-voltage detection.  
P3 : IGBT gate interrupt.  
P4 : Fault signal generation.  
P5 : Under-voltage reset.  
P6 : Normal operation: IGBT ON and conducting current.

**Figure 9. Under-Voltage Protection (Low-Side)**



- P1 : Normal operation: IGBT ON and conducting current.  
P2 : Under-voltage detection.  
P3 : IGBT gate interrupt.  
P4 : No fault signal.  
P5 : Under-voltage reset.  
P6 : Normal operation: IGBT ON and conducting current.

**Figure 10. Under-Voltage Protection (High-Side)**



- P1 : Normal operation: IGBT ON and conducting current.  
P2 : Short-circuit current detection.  
P3 : IGBT gate interrupt / fault signal generation.  
P4 : IGBT is slowly turned off.  
P5 : IGBT OFF signal.  
P6 : IGBT ON signal: but IGBT cannot be turned on during the fault-output activation.  
P7 : IGBT OFF state.  
P8 : Fault-output reset and normal operation start.

Figure 11. Short-Circuit Protection (Low-Side Operation Only)

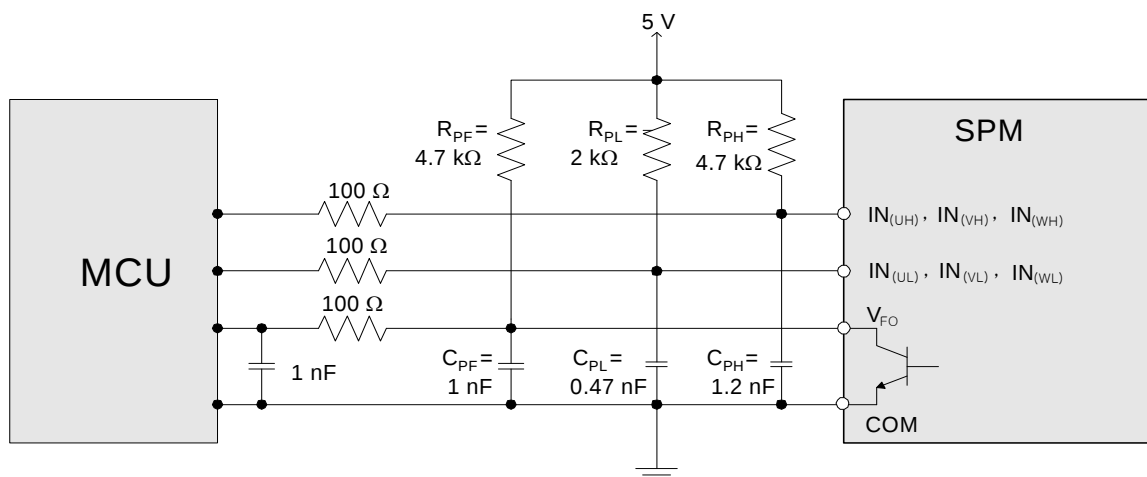
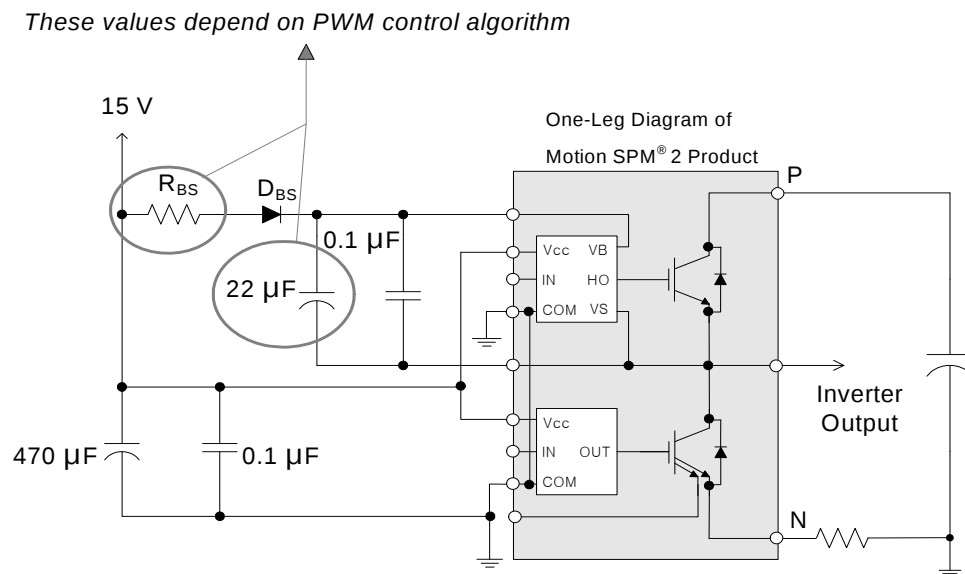


Figure 12. Recommended MCU I/O Interface Circuit

3rd Notes:

1. It would be recommended that by-pass capacitors for the gating input signals,  $IN_{(UL)}$ ,  $IN_{(VL)}$ ,  $IN_{(WL)}$ ,  $IN_{(UH)}$ ,  $IN_{(VH)}$  and  $IN_{(WH)}$  should be placed on the Motion SPM® 2 product pins and on the both sides of MCU and Motion SPM 2 Product for the fault output signal,  $V_{FO}$ , as close as possible.
2. The logic input works with standard CMOS or LSTTL outputs.
3.  $R_{PL}C_{PL}/R_{PH}C_{PH}/R_{PF}C_{PF}$  coupling at each Motion SPM 2 product input is recommended in order to prevent input/output signals' oscillation and it should be as close as possible to each of Motion SPM 2 Product pins.



**Figure 13. Recommended Bootstrap Operation Circuit and Parameters**

**3rd Notes:**

4. It would be recommended that the bootstrap diode,  $D_{BS}$ , has soft and fast recovery characteristics.
5. The ceramic capacitor placed between  $V_{CC}$  - COM should be over  $0.1\ \mu\text{F}$  and mounted as close to the pins of the Motion SPM® 2 product as possible.

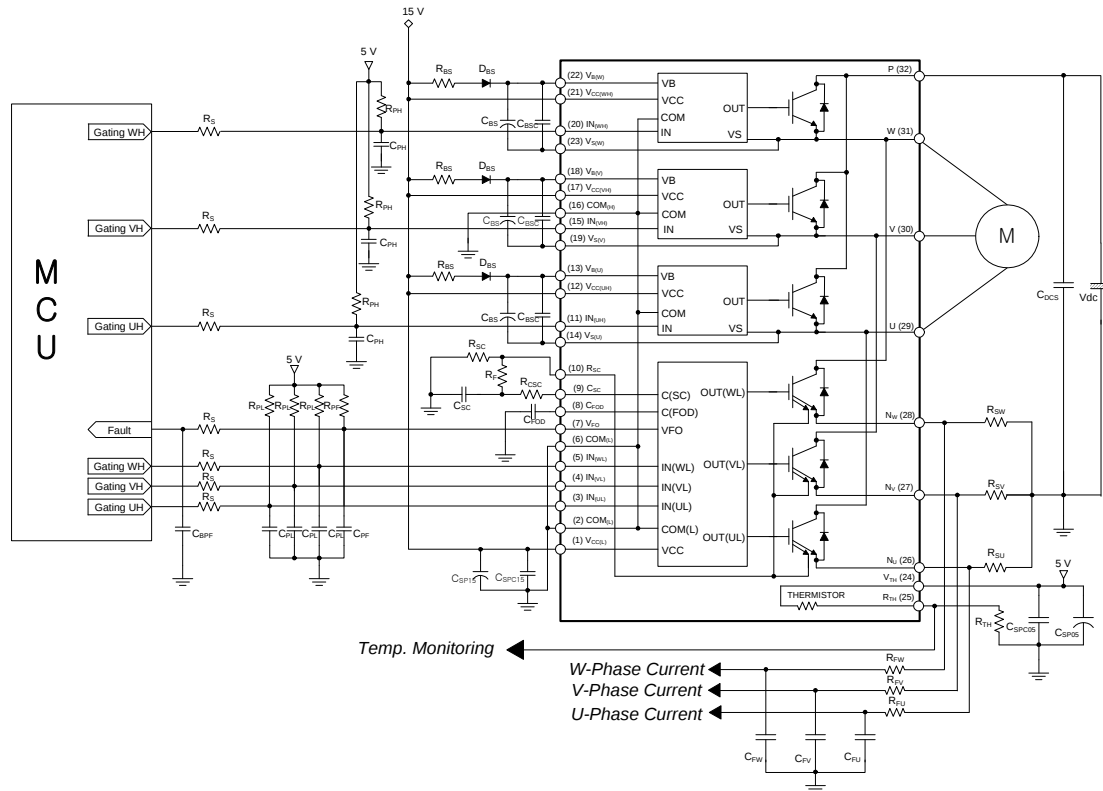
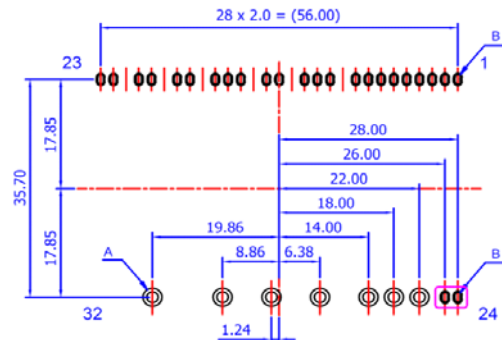
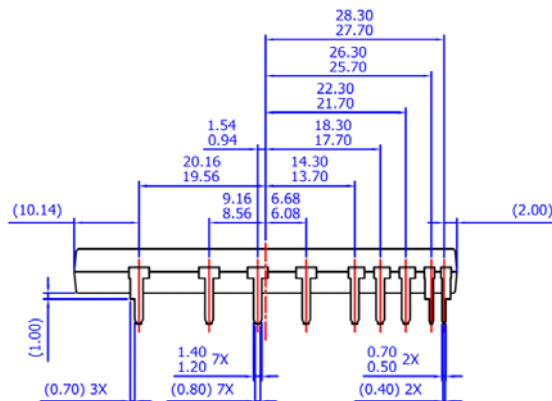
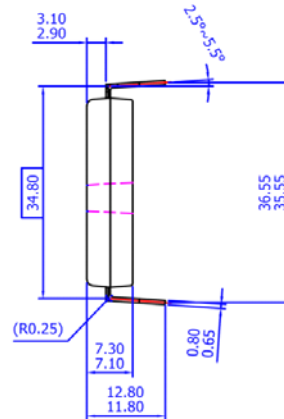
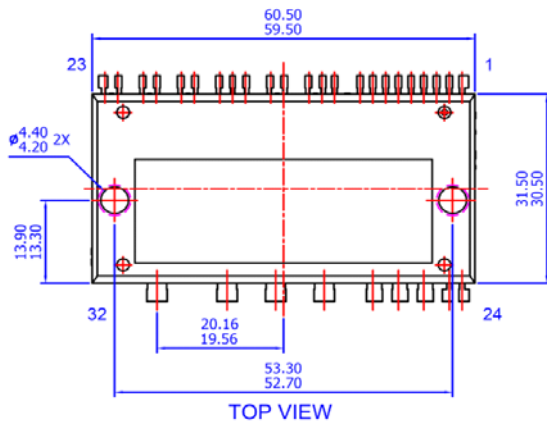
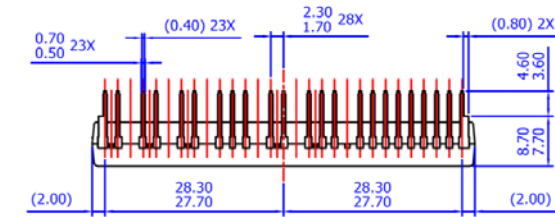


Figure 14. Application Circuit

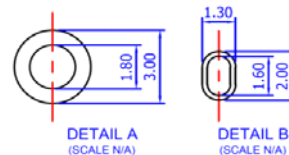
4th Notes:

1.  $R_{PL}C_{PL}/R_{PH}C_{PH}/R_{PF}C_{PF}$  coupling at each Motion SPM® 2 product input is recommended in order to prevent input signals' oscillation and it should be as close as possible to each Motion SPM 2 product input pin.
2. By virtue of integrating an application specific type HVIC inside the Motion SPM 2 product, direct coupling to MCU terminals without any optocoupler or transformer isolation is possible.
3.  $V_{FO}$  output is open-collector type. This signal line should be pulled up to the positive side of the 5 V power supply with approximately 4.7 k $\Omega$  resistance. Please refer to Figure 12.
4.  $C_{SP15}$  of around seven times larger than bootstrap capacitor  $C_{BS}$  is recommended.
5.  $V_{FO}$  output pulse width should be determined by connecting an external capacitor ( $C_{FOD}$ ) between  $C_{FOD}$ (pin 8) and  $COM_{(L)}$ (pin 2). (Example : if  $C_{FOD} = 33$  nF, then  $t_{FO} = 1.8$  ms (typ.)) Please refer to the 2nd note 6 for calculation method.
6. Each input signal line should be pulled up to the 5 V power supply with approximately 4.7 k $\Omega$  (at high side input) or 2 k $\Omega$  (at low side input) resistance (other RC coupling circuits at each input may be needed depending on the PWM control scheme used and on the wiring impedance of the system's printed circuit board). Approximately a 0.22 ~ 2 nF by-pass capacitor should be used across each power supply connection terminals.
7. To prevent errors of the protection function, the wiring around  $R_{SC}$ ,  $R_f$  and  $C_{SC}$  should be as short as possible.
8. In the short-circuit protection circuit, please select the  $R_fC_{SC}$  time constant in the range 3 ~ 4  $\mu$ s.
9. Each capacitor should be mounted as close to the pins of the Motion SPM 2 product as possible.
10. To prevent surge destruction, the wiring between the smoothing capacitor and the P & N pins should be as short as possible. The use of a high frequency non-inductive capacitor of around 0.1 ~ 0.22  $\mu$ F between the P&N pins is recommended.
11. Relays are used at almost every systems of electrical equipments of home appliances. In these cases, there should be sufficient distance between the MCU and the relays. It is recommended that the distance be 5 cm at least.

## Detailed Package Outline Drawings



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